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Metrology of $Ar - N_2/O_2$ Mixture Atmospheric Pressure Pulsed DC Jet Plasma and its Application in Bio-Decontamination

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ABSTRACT: Atmospheric pressure plasma jets are gaining a lot of attention due to their widespread applications in the field of bio-decontamination, polymer modification, material processing, deposition of thin film, and nanoparticle fabrication. Herein, we are reporting the disinfection of *Pseudomonas aeruginosa*, *Staphylococcus aureus*, and *Escherichia coli* bacteria using plasma jet. In this regard, Ar–O₂, Ar–N₂, and Ar–O₂–N₂ mixture plasma is generated and characterized using optical and electrical characterization. Variation in plasma parameters like electron temperature, electron density, and reactive species production is monitored with discharge parameters such as applied voltage and feed gas concentration. Results show that the peak average power consumed in Ar–O₂, Ar–N₂, and Ar– O₂–N₂ mixture plasma is found to be 4.45, 2.93, and 4.35 W respectively, at 8 kV. Moreover, it is noted that by increasing applied voltage, the electron temperature, electron density, and reactive species production also increases. It is worth noting



that electron temperature increases with increase in oxygen concentration in the mixture $(Ar - O_2)$, while it decreases with increase in nitrogen concentration in the mixture $(Ar-N_2)$. Similarly, a decreasing trend in electron temperature is noted for $Ar-O_2-N_2$ mixture plasma. On the other hand, a decreasing trend in electron density is noted for all the mixtures. Reduction in viable colonies of *Pseudomonasaeruginosa, StaphylococcusAureus*, and *Escherichiacoli* were confirmed by the serial dilution method. The inactivation efficiency of pulsed DC plasma generated, in the $Ar-N_2$ mixture at 8 kV and 6 KHz, was evaluated against *P. aeruginosa, S. aureus* and *E. coli* bacteria by measuring the number of surviving cells versus plasma treatment time. Results showed that after 240 s of plasma treatment, the number of survival colonies of the mentioned bacteria was reduced to less than 30 CFU/mL.

■ INTRODUCTION

Laboratory plasma has become a subject of great interest for a wide range of applications in various fields.¹⁻⁴ In industries, plasma is used in etching and synthesis of advanced materials,^{5,6} synthesis of nanomaterials,^{7,8} enhancement of electrical properties of semiconductor,⁹ surface modification,¹⁰ coating,¹¹ cleaning,¹² plasma-enhanced chemical vapor deposition of thin film solar cells,¹³ processing of wastes,¹⁴ water purification,¹⁵ carbon dioxide dissociation and activation,¹⁶ and so forth. Concerning medical application, plasma technologies are further divided into two categories:

- 1. Processing of surfaces, sterilization, and disinfection of bio-relevant instruments to achieve desired qualities for therapeutic purposes subsequently.
- 2. Direct interaction of plasma with human or animal organs for specific medical treatments.

Plasma-based treatments of medicinal instruments to modify their biocompatibility and to improve the polymer surfaces are largely studied to meet the criteria for cell culturing and tissue engineering.^{17–19} Pioneer applications of plasma in medicinal field were sterilization and sanitization of medical equipment. Plasma technology showed brilliant results in sterilization, bacterial disinfection, and decontamination processes. The plasma-assisted disinfection techniques were made more advanced, and the field of dermatology was further explored.^{20–22} Cold atmospheric pressure plasma has proven its anti-cancer effect in numerous in vitro and in vivo studies.²³ Similarly in dentistry, plasma research showed remarkable results in tooth whitening, removal of plaque, dental apparatus sterilization, bacterial disinfection, and in composite regeneration.²⁴

Researchers throughout the globe are contributing to medical plasma.^{25–32} However, physical and chemical impacts of plasma which play a vital role in medicine are still difficult to understand. Moreover, the bio-relevant targets which are used

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Figure 1. (a) Schematic diagram of the experimental setup; (b) real-time discharge in developed KINPen (photograph courtesy of "Naqib Ullah". Copyright 2023).



Figure 2. Current-voltage waveform of discharge at 8 kV voltage and 6 kHz fixed pulsed frequency in (a) Ar-O2 and (b) Ar-N2 mixture plasmas.

in treatment are quite complex due to various unmeasured and mysterious variables.³³⁻³⁵ However, atmospheric pressure plasma comprises of reactive nitrogen and oxygen species (RNOS), having gas temperature close to ambient temperature, and is suitable for biomedical applications.³⁶⁻⁴¹ In addition to RNOS, UV radiation and transient electric fields are also likely important in plasma-based disinfection.⁴² Tuning of these parameters at ambient temperature is always a challenge due to high electron neutral collision rates. Numerous atmospheric pressure devices have been developed to generate the room temperature plasma for medical and industrial applications.⁴⁸⁻⁵³ Investigation on plasma devices emphasizing on biomedical applications has shown that plasma devices can be economical and convenient.⁵⁴ In these devices, discharge parameters influence the biological sample, which can be controlled via plasma parameters like input power, treatment time, treatment distance, feed gas composition, and mode of operation.⁵³

The primary objective of the present study is to optimize plasma parameters, that is, electron number density, electron temperature, and power consumed in terms of discharge parameters, that is, applied voltage and gases concentrations, for inactivation of different pathogenic bacteria (*Pseudomonas* Aeruginosa, StaphylococcusAureus, and Escherichiacoli). To study the effect of molecular gases concentrations on plasma parameters, the total flow rate (1500 SCCM) of the mixture is kept constant, while the molecular gas content is varied as follows: in Ar–O₂ plasma, the O₂ concentration is varied from 5 to 50% of the total flow rate; in Ar–N₂ plasma, the N₂ concentration is varied from 5 to 50% of the total flow rate; and in Ar–O₂–N₂ plasma, the O₂ and N₂ have equal flow rates; the O₂ + N₂ concentration is varied from 5 to 50% of the total flow rate.

To understand the kinetics of the discharge, optical emission spectroscopy (OES) and electrical characterization techniques are employed. Electron density is estimated by using physical– electrical and Stark broadening techniques. Average power consumed per pulse is calculated from electrical measurements. Normalized intensities of RNOSs, UV radiation, and electron temperature are monitored as function of discharge parameters.

EXPERIMENTAL SETUP

The schematic diagram of experimental setup is shown in Figure 1. A home-made cylindrical plasma jet with the source



Figure 3. Evolution of (a) instantaneous discharge power at 8 KV and (b) average discharge power verses applied voltage in $Ar-O_2$, $Ar-N_2$, and $Ar-O_2-N_2$ mixture plasma, recorded at 6 kHz frequency and 1500 SCCM total gas flow rate.

tube of length 90 mm, operating at atmospheric pressure was used to generate the plasma. The outer body of the source tube, served as the cathode, was made of stainless-steel of diameter 16 mm, while the inner diameter was 12 mm. To make it electrical safe, a Teflon rod, of outer diameter 12 mm, was inserted in the stainless-steel pipe. For dielectric barrier discharge (DBD) configuration a quartz tube of outer diameter 4 mm and inner diameter 2 mm was fixed in the Teflon rod. A copper wire, serving as the anode, was inserted through this quartz tube. To generate the plasma, a nanosecond pulse DC power supply (FPG10-10NM10) was used, at a fixed frequency of 6 kHz while the applied voltage was varied from 4 to 8 kV with a step of 1 kV. To monitor the effect of gases' flow rate on plasma parameters, it was varied up to 1500 SCCM with Teledyne digital mass flowmeters.

OES was employed to record the time-integrated emission spectra as a function of discharge parameters. The emission spectra of the discharge were recorded using a set of collimated lens and optic fiber (FC5-UV/IR200-2-ME), positioned at the right angle to the discharge, and connected to high resolution spectrometer (AVANTES-RACKMOUNT-USB2). These five furcated spectrometers were equipped with five gratings with a bandwidth of 250-900 nm. The first two gratings have 2400 lines/mm, next two have 1800 lines/mm, and the last one has 1200 lines/mm. The respective resolution varies from 0.06 to 0.13 nm. The TOSHIBACCD (Linear array 3648DUV) detector of 8 μ m pitch was installed in the spectrometer. A high voltage probe (TESTECTT-HVP2739) with a bandwidth of DC-220 MHz and the current probe (GwINSTEKGCP-530) with a bandwidth of DC-50 MHz were used to monitor the voltage and current characteristics of the discharge. To avoid the reflection effect, on recorded traces, a suitably long transmission line was used. Moreover, to measure the net applied voltage of the discharge, measurements were carried out very close to the electrodes.

RESULTS AND DISCUSSION

Electrical Characterization of the Discharge. Figure 2 shows the recorded voltage and current waveforms of discharge, in plasma jet, as a function of time, for (a) $Ar-O_2$ (Ar 1000 SCCM, O 2500 SCCM) and (b) $Ar-N_2$ (Ar-1000

SCCM and N2-500 SCCM) mixture plasma, at 8 kV applied voltage and 6 kHz fixed frequency.

A GWInstek3000 series four channel oscilloscope (GDS-3504), having 500 MHz bandwidth and 4 Gsample/second real time sampling rate, was used to record waveforms for each pulse of voltage and corresponding discharge current. The pulsating DC power supply has a rise time of 2-3 ns and uses a square wave of pulse width 10 ns and 50% duty cycle as the input signal to initiate the discharge, but the output signals from the load collected via an oscilloscope were quite different. This may be referred to as the mismatch of impedance between load (discharge) and power supply, which results in multiple harmonics of the applied signal inside the plasma. The repetitive voltage and current signals confirm that the pulsed supply is well adapted to the charge setup. The influence of electromagnetic perturbations on the shape of pulse waveforms and the reflection of power back to cable are also visible (Figure 2) in terms of some kV amplitudes, which appear after 20 ns, but these perturbations are not influencing adequately the discharge performance. It is clear from the figure that the current waveforms are in phase with the voltage waveforms peaks. The positive current peaks at the rising and falling ends of the voltage peak are formed due to the propagation of charges from the power electrode to the surface of the dielectric barrier within the plasma. The dropping regime of current appears when pulse voltage starts to decrease from its highest amplitude to zero. These negative peaks of current appear when the charges are collected back by the power electrode.

Power Consumed. By using these IV curves, the average discharge powers can be calculated by taking area under the curve using eq 1.

$$P_{\text{ave}} = \frac{1}{T} \int_0^t V(t) I(t) dt \tag{1}$$

where *T* is the time period of applied frequency, and V(t) and I(t) are the voltage and current traces recorded using voltage and current probes respectively. For estimation of average power, the recorded V(t) and I(t) traces were integrated for pulse duration of 20 ns. The term power here refers only to the



Figure 4. Optical emission spectra of (a) $Ar-O_2$, (b) $Ar-N_2$, (c) $Ar-O_2-N_2$, and (d) normalized intensities of UV radiation, reactive nitrogen, and oxygen species, recorded at 8 kV applied voltage, 6 kHz fixed frequency, and 1500 SCCM flow rate.

power consumed, which is obtained as a product of energy per pulse (Joules) and supply frequency (kHz).

Different maximum instantaneous powers (Figure 3a), for example, 88, 74, and 80 kW are measured for Ar-O₂, Ar-N₂, and Ar-O2-N2 mixtures, respectively, for a fixed applied voltage of 8 kV. The area under the curve of these instantaneous power versus time graphs gives the energy consumed per pulse in Joules for a particular combination of supply voltage and frequency. This energy per pulse is multiplied by the supply frequency to obtain the average power consumed by the device in Watt (W). The maximum average power consumed in Ar-O2, Ar-N2, and Ar-N2-O2 mixtures discharges are 4.45, 2.93, and 4.35 W, respectively, at 8 kV applied voltage (Figure 3b) under the similar discharge conditions. It is clear from Figure 3b that the $Ar-O_2$ mixture consumes large average power compared to Ar-N2 and Ar- $O_2 - N_2$ mixtures. The difference in power consumed by the device when different working gasses are used is due to the various ionization mechanisms of different gases. In Ar-O2 plasma, due to the high electron affinity of oxygen, the plasma resistance increased and require more power to sustain the discharge as compared to Ar-N2 plasma. Furthermore, the oxygen gas is electronegative in nature and the loss of electrons

due to diffusion and attachment to oxygen molecules in $Ar-O_2$ plasma requires high electric field strength inside the plasma than $Ar-N_2$ plasma to produce enough electrons to sustain the discharge.

Optical Emission Spectroscopy. Identification of Spectra. In non-thermal plasmas, the ion temperature is almost equal to room temperature, whereas the electron temperature is around a few thousand kelvin. These energetic electrons are responsible for plasma generation via electron impact excitation and ionization. Besides this, these energetic electrons play a crucial role in the generation of reactive species by dissociating the molecules into atoms. RNOs, nitrogen oxides (N_xO_y) , hydroxyl radicals (OH), ozone (O_3) , and molecular ions can be formed by electron impact.^{56–58}

In the present study, OES was carried out to understand the ongoing process in the generated plasma. The emission spectra of $Ar - O_2(Ar - 1000 \text{ SCCM} \text{ and } O_2 - 500 \text{ SCCM})$, $Ar - N_2(Ar - 1000 \text{ SCCM} \text{ and } N_2 - 500 \text{ SCCM})$ a n d $Ar - O_2 - N_2(Ar - 1000 \text{ SCCM}, O_2 - 250 \text{ SCCM})$ and $N_2 - 250 \text{ SCCM}$ and $N_2 - 250 \text{ SCCM}$

gases mixtures, in the active plasma region, recorded at 8 kV

applied voltage, 6 kHz frequency and 1500 SCCM total gas flow rate, are shown in Figure 4.

In Ar-O₂ plasma discharge, highly reactive atomic oxygen species comprising of (a) 3s³S-3p³P around 844.6 nm, (b) 3s³D-3p³D around 823.3 nm, (c) 3s⁵S-3p⁵P around 777.4 nm, (d) $3s^{1}D-3p^{3}P$ around 715.7 nm, and (e) $3p^{5}P-4d^{5}D$ around 615.8 nm along with Ar-I and Ar-II lines are detected. The first negative system of O2 molecule $O_2^+ (b^4 \Sigma_g^- - a^4 \Pi_u)^{59}$ in the spectral range of 596–609 nm is shown in Figure 4a. It is worth noting that the probability of dissociation of O₂ through collision with electrons is quite low because O₂ has a high electronegative nature.⁶⁰ The one possible reaction is that the energetic electrons first excite the Ar atoms to some highly excited metastable state which, through collisions with O2 molecules, transfer energy to O2 molecules to either dissociate or even ionize them to O_2^+ . The second possibility is that the Ar atoms transfer their energy to O₂ molecules and O₂ molecules become super excited. This super excited molecule can dissociate into O* and O as

$$e^* + \operatorname{Ar} \to \operatorname{Ar}^* + e \tag{2}$$

$$Ar^* + O_2 \to O_2^{**} + Ar$$
 (3)

$$O_2^{**} \to O^* + O \tag{4}$$

Alternatively, super excited molecules could first autoionize to form an O_2^+ ion; then the O_2^+ ion captures an electron and dissociates into O atoms as reported in literature⁶¹

$$O_2^{**} \to O_2^+ + e \tag{5}$$

$$e + O_2^+ \to O + O \tag{6}$$

$$e + O_2^+ \to O^+ + O + e \tag{7}$$

Figure 4b shows the normalized emission intensities in Ar– N₂ mixture plasma; 16 different multiplets of N atoms: (a) 3 transitions at 742.3, 744.2, and 746.8 nm associated with 3s⁴P–3p⁴S, (b) 5 transitions at 818.5, 820, 821.6, 822.3, and 824.2 nm associated with 3s⁴P–3p⁴P, (c) 4 transitions at 856.8, 859.4, 862.9, and 856.6 nm associated with 3s²P–3p²P, and (d) 4 transitions at 868, 870.3, 871.2, and 871.9 nm associated with 3s⁴P–3p⁴D are observed. The emission spectra in the UV region composed of the NO band at (258.6 nm), with electronic transition (NO($A^2\Sigma^+ - X^2\Pi_r)$), N₂ second positive system at (315–380 nm), with electronic transition ($N_2(C^3 \pi_u - B^3 \pi_g)$), and N₂ first negative system at N₂⁺(391– 428 nm) with electronic transition (N₂ ($B^2\Sigma_u - X^2\Sigma_g$)) are clearly visible in Figure 4b.

These predominant bands of NO, N₂ ($C^3\Pi_u$), and N₂⁺ ($B^2 \Sigma_u^+$) are excited as^{62,63}

$$NO(X^{2}\Pi) + N_{2}(A^{3}\Sigma_{u}^{2}) \rightarrow N_{2}(X^{2}\Sigma_{g}) + NO(A^{2}\Sigma^{+})$$
(8)

$$NO(A^2\Sigma^+) \to NO(X^2\Pi) + h\nu$$
 (9)

$$N_2(X^1\Sigma_g^+) + e^* \to N_2(C^3\Pi_u) + e$$
 (10)

$$N_2(X^1 \Sigma_g^+) + Ar^* ({}^3P_2, {}^3P_2) \to N_2(C^3 \Pi_u) + Ar$$
(11)

$$N_2(X^1\Sigma_g^+) + e \to N_2^+(B^2 \Sigma_u^+) + 2e$$
 (12)

Further, OES analysis revealed that Ar peaks are more dominant over other species such as oxygen and nitrogen. Since a higher flow of argon was introduced in the APPJ device, the bright purple color can be attributed to this dominant species.

- (1) The transition involving singlet, triplet, and quintet levels is observed.
- (2) The transition between quintet levels of oxygen is higher than the transition between triplet levels.

The normalized intensities of UV radiation and reactive species plotted (on log scale graph) for a fixed applied voltage of 8 kV in different $Ar-O_2$, $Ar-N_2$, and $Ar-N_2-O_2$ mixture plasma are shown in Figure 4d. It is clear from the figure that in $Ar-O_2$ plasma, the UV radiation is negligible; the reactive nitrogen species intensities are moderate while reactive oxygen species intensities of UV radiation and reactive nitrogen species are considerably high and also the reactive oxygen species intensities are moderate. For $Ar-O_2-N_2$ mixture plasma, the intensities of UV radiation and RNOs lie in between the $Ar-O_2$ and $Ar-N_2$ plasma. Since the concentrations of UV radiation and RNOs are more appropriate for plasma-based disinfection, $Ar-N_2$ mixture plasma is employed for selected bacterial inactivation in this study.⁶⁴

Electron Temperature. To control the production and destruction rates of reactive species in a plasma, accurate knowledge about the electron temperature is mandatory because these rates are the function of electron temperature. In the present study, electron temperature is estimated via the Boltzmann plot method based on the OES technique.⁶⁵ In this method, different lines of Ar–I are selected by assuming that these lines are populated according to Boltzmann distributions.⁶⁶ Table 1 shows the selected Ar–I lines used to estimate

 Table 1. Spectroscopic Data of Ar–I Transition Used in the

 Boltzmann Plot for Electron Temperature Measurement

wavelength (nm)	$A_{\rm k}(10^6 {\rm S}^{-1})$	$g_{\rm k}$	$E_{\rm k}$ (eV)
727.29	1.83	3	13.32
738.39	08.5	5	13.30
750.38	45.0	1	13.48
751.40	40.0	1	13.27
763.51	24.5	5	13.17
772.42	11.7	3	13.33
794.82	18.6	3	13.28
800.61	04.9	5	13.17
801.47	09.3	5	13.09
810.37	25.0	3	13.15
811.53	33.0	7	13.07
826.45	15.3	3	13.32
840.82	22.3	5	13.30
842.46	21.5	5	13.09

the electron temperature, whereas the relevant spectroscopic data are taken from literature.⁶⁷ The transitions from Ar-I lines used to calculate the electron temperature are given in Table 1.

The dependency of electron temperature on applied voltage in $Ar-O_2$, $Ar-N_2$, and $Ar-N_2-O_2$ mixture plasma is plotted in Figure 5a. An increasing trend in electron temperature is noted with increasing applied voltage, which is because the power consumption increases with increasing applied voltage.



Figure 5. Variations of electron temperature (at 8 kV applied voltage, 6 kHz fixed frequency, and 1500 SCCM gas flow) vs (a) applied voltages and (b) molecular gas concentration.



Figure 6. Variations of electron number density (at 8 kV applied voltage, 6 kHz fixed frequency, and 1500 SCCM flow rate) vs (a) applied voltages and (b) molecular gas concentration.

Furthermore, electron temperature has higher value in $Ar-O_2$ plasma as compared to $Ar-N_2$ plasma and $Ar-O_2-N_2$ plasma because $Ar-O_2$ plasma consumes more power than the remaining two types of plasmas, as shown in Figure 3b.

The electron temperature versus varying molecular gas concentrations is plotted in Figure 5b. In the case of $Ar-O_2$ plasma, increasing O_2 concentration results in increasing electron temperature, which may be due to the fact that increasing O_2 concentration reduces plasma excitation, especially in the UV region, so the consumed power is utilized to enhance the electron temperature.⁶⁸ In the case of $Ar-N_2$ and $Ar-O_2-N_2$ plasma, the decreasing nitrogen concentration, which is because introducing nitrogen to argon plasma enhances the excitation and ionization in the UV region (Figure 4).⁶⁹ These enhanced excitations and ionization in the UV region, with the increasing N₂ concentration in the mixture, are due to higher electron impact cross section of nitrogen.⁶⁵ Hence, with the addition of nitrogen in the mixture,

lower electron temperature is noted. Moreover, Penning excitation of the N_2 second positive system of nitrogen with a Ar metastable state also becomes predominant, and thus, a decrease in electron temperature is noted.⁷⁰

Electron Number Density. In several dielectric media, the electrical phenomena are mostly related with the development and propagation of ionization waves. These waves play a vital role in the pre-breakdown processes and can be seen in a variety of pulsed electrical discharges like, DBD, coronal discharge, and lightning flashes.^{71,72} Cold atmospheric pressure plasma jets have recently been discovered to exhibit similar phenomena associated to the rapid propagation of plasma luminous particles (plasma bullets/streamers).^{73–75} In these discharges, plasma excitation is due to ionization wave propagation where space charge electric field plays a key role. To measure this electric field, one needs to solve the Boltzmann equation when plasma approximation is not valid. However, at low frequency (used in this study), one can measure the electric field using Laplacian ($E = -\nabla v / \nabla r$) as a



Figure 7. (a) Recorded Ar–I 763.5 nm line and Voigt Fit, (b) electron density vs applied voltage, and (c) electron density vs molecular gas concentration (at 8 kV applied voltage, 6 kHz fixed frequency, and 1500 SCCM total gas flow).

first approximation. The same is used to estimate the electron density using physical electrical measurement as

$$N_{\rm e} = \frac{J}{\mu_{\rm e} eE} \tag{13}$$

where N_e is electron number density, *J* is current density, μ_e is the mobility of electrons, *e* is a charge on the electron, and *E* is the electric field.⁷⁶ The variation of electron number density with different applied voltages and molecular gas content is shown in Figure 6.

It is clear from Figure 6 that the number density increases with an increase in applied voltage and decreases with increasing molecular gas concentration. This is because, at the higher applied voltage, the discharge current increases due to higher intensity of electric fields. As a result, the ionization rate of neutral species increases, which in turn is responsible for the increase in electron number density. Moreover, with increasing molecular gas concentration in the plasma, the energy transformation from electrons to molecules through vibrational and rotational excitations becomes more pronounced.⁷⁷ As a result, electron impact ionization decreases, as shown in Figure 6b. Further, the electron density in $Ar-O_2$ mixture plasma is higher than that of the $Ar-N_2$ and $Ar-O_2-N_2$ gaseous mixture plasmas. This is because the ionization energy of N_2 molecule is higher compared to the O_2 molecule.

Electromagnetic perturbations can influence the shape of pulse waveforms and may cause the inconsistency in the physical electrical measurement of electron number density. To overcome these limitations and for the sake of comparison, the electron number density is also measured with the "Stark broadening Technique" based on the OES. The Stark broadening mechanism is commonly used to measure the electron number density from the spectral line and is considered a significant non-intrusive plasma diagnostic technique.⁷⁸ In the absence of hydrogen lines, the neutral lines exhibit the quadratic Stark effect, and the relationship between electron number density and Stark broadening is given as.^{79,80}



Figure 8. Growth of *E. coli* (a) 10⁵ CFU/mL, (b) 10⁷ CFU/mL, (c) 10⁹ CFU/mL, and (d) treated for 240 s (photograph courtesy of "Naqib Ullah". Copyright 2023).

$$\Delta \lambda_{1/2} = 2\omega \left(\frac{N_{\rm e}}{10^{16}}\right) + 3.5A \left(\frac{N_{\rm e}}{10^{16}}\right)^{1/4} \left[1 - \frac{3}{4} N_{\rm D}^{-1/3}\right]$$
$$\omega \left(\frac{N_{\rm e}}{10^{16}}\right) \tag{14}$$

1 / 4

where ω represents the electron impact width parameter, $N_{\rm e}$ denotes electron number density, A is the ion broadening parameter, and $N_{\rm D}$ is the number density of the Debye sphere. The first term of the abovementioned equation is due to electron's impact on broadening, while the second term is due to the ion's impact. In dense plasma, the non-hydrogenic isolated neutral atom is broadened by electron's impact, then the expression becomes

$$\Delta\lambda_{1/2} = 2\omega \left(\frac{N_{\rm e}}{10^{16}}\right) \tag{15}$$

Numerous Ar I lines have been identified in the spectrum. The Ar I line at the 763.5 nm line is well evident, isolated, and also sensitive to the quadratic Stark effect and thus selected for electron density measurements based on OES.⁷⁷ Figure 7a shows the Voigt profile of the selected Ar I line. The value fwhm of the profile gives the Stark broadening, whereas the value of ω for Ar I 763.5 nm line is taken from literature.⁷⁷

It is evident from the figure that the electron density measured via Stark broadening (eq 15) has one order value $(10^{16} \text{ cm}^{-3})$ as compared to density measured via electrical measurement (eq 13). The trend for density versus molecular gas content is similar as electrical measurements. It is worth noting that from 4 to 6 kV, the electron density increases rapidly, but the electron temperature is almost constant, while from 6 to 8 kV, the electron density is almost constant, but the electron temperature increases.

Bacterial Inactivation. To check the efficiency of Ar-N₂ mixture plasma in sterilization of pathogenic bacteria, preferred suitable condition, that is, $(Ar1000 \text{ SCCM} - N_2 500 \text{ SCCM})$ at 8 kV and 6 kHz frequency, for various exposure time was tested. For this purpose, three different bacteria (Pseudomonas aeruginosa, Staphylococcus aureus, and Escherichia coli) were selected. A bacterial suspension was prepared for P. aeruginosa bacteria with specific concentrations. 0.1 mL of an overnight broth of *P. aeruginosa* was taken (roughly containing 10⁹ CFU/ mL, CFU stands for colony forming units) from the prepared solution and evenly spread over the Petri dish. The Petri dish was placed on a DC gear motor to rotate under the plasma jet so that a larger area may interact with the plasma plume and each segment of the sample be uniformly treated. The serial dilution method was employed to dilute to the desired number of colonies and also for counting the viable colonies before and after plasma treatment. A similar procedure was repeated for S. aureus and E. coli. Each experiment was repeated at least three

times, and the standard deviations are calculated. The growth of *E.coli* for various concentrations and after plasma treatment is shown in Figure 8.

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Primary tests of the $Ar-N_2$ mixture plasma jet sterilization of pathogenic bacteria were executed to evaluate the effect of plasma sterilization of bacteria resistant to antibiotics. In the first step, the efficacy was checked for different motor speeds (0.5-50 rpm). It was found that the number of survival colonies was less with a 6 rpm speed. The number of survival colonies at different treatment times is shown in Figure 9. It is



Figure 9. Number of survival colonies after $Ar-N_2$ (Ar-1000 SCCM and N_2 -500 SCCM) plasma treatment at 8 kV voltage and 6 kHz frequency.

clear from the figure that the selected pathogenic bacteria deactivated with plasma treatment and exposure time. After 240 s, the number of survival colonies is reduced to less than 30.

CONCLUSIONS

Electrical and optical characterization of $Ar-O_2$, $Ar-N_2$, and $Ar-O_2-N_2$ mixture plasma was carried out. The average power consumed was estimated at 4.45, 2.93, and 4.35 W, respectively. The emission spectrum reveals that in $Ar-O_2$ plasma, the UV radiation is negligible; normalized reactive nitrogen intensities are moderate, while normalized reactive oxygen species intensities are high. However, in $Ar-N_2$ mixture plasma, the normalized intensities of UV radiation and reactive nitrogen species are considerably high; also, the normalized reactive oxygen species intensities are moderate. For $Ar-O_2-N_2$ mixture plasma, the normalized intensities are moderate. For $Ar-O_2-N_2$ mixture plasma, the normalized intensities of UV radiation and RNOs lie in between the $Ar-O_2$ and $Ar-N_2$.

plasma. Electron temperature increases with increasing voltage and increasing oxygen concentration in the mixture. On the other hand, increasing nitrogen concentration in the mixture causes a decrease in electron temperature. The electron density calculated from physical electrical technique shows an increasing trend with applied voltage, but a decreasing trend is noted by increasing molecular gas content. A similar trend was observed by estimating electron density via the OES-Stark broadening method. The electron density ($10^{14} - 10^{15}$) estimated from physical electrical technique is one order less than the electron density (10^{16}) derived from OES-Stark broadening mechanism. The deactivation of *P. aeruginosa, S. aureus*, and *E. coli* was reported with the application of Ar–N₂ mixture plasma.

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Notes

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